

Hyperfast Rectifier, 2 x 5 A FRED Pt®



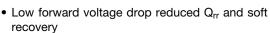
DESIGN SUPPORT TOOLS AVAILABLE



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5 A			
V_{R}	100 V			
V _F at I _F	0.74 V			
t _{rr} (typ.)	16 ns			
T _J max.	175 °C			
Package	SlimDPAK (TO-252AE)			
Circuit configuration	Common cathode			

FEATURES

- · Hyperfast recovery time
- 175 °C max. operating junction temperature





- Low leakage current
- Very low profile typical height of 1.3 mm
- · Ideal for automated placement
- · Polyimide passivation for high reliability standard
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyper fast recovery rectifiers designed with optimized performance of forward voltage drop, hyper fast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V_{RRM}		100	V
A	per leg	I _{F(AV)}	T _C = 165 °C	5	
Average rectified forward current	per device			10	Α
Non-repetitive peak surge current	per leg	I _{FSM}	$T_J = 25$ °C, 10 ms sine pulse wave	100	
Operating junction and storage temp	peratures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	100	-	-		
		I _F = 5 A	-	0.90	1.04		
Forward voltage V _F	V	I _F = 10 A	-	1.0	1.17	V	
	VF	I _F = 5 A, T _J = 150 °C	-	0.74	0.84		
	I _F = 10 A, T _J = 150 °C	-	0.85	1.05			
Reverse leakage current per leg		$V_R = V_R$ rated	-	-	4		
	I _R	T _J = 150 °C, V _R = V _R rated	-	=	80	μΑ	
Junction capacitance per leg	C _T	V _R = 100 V	-	17	=	pF	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		ı	16	-	
Reverse recovery time	t _{rr}	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{RR} = 0.25 \text{ A}$		-	-	25]
		T _J = 25 °C	$I_F = 5 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 160 \text{ V}$	-	21	-	ns
		T _J = 125 °C		-	30	=	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	2.5	-	Α
		T _J = 125 °C		-	4	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	25	-	~C
		T _J = 125 °C]	-	60	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to ambient	R _{thJA} (1)(2)		-	73	90	°C/W
Thermal resistance, junction to case, per diode	R _{thJC} ⁽³⁾		-	2.1	2.5	C/VV
Marking device		Case style SlimDPAK (TO-252AE)	10CVH01			

Notes

- $^{(1)}$ The heat generated must be less than thermal conductivity from junction to ambient; $dP_D/dT_J < 1R_{thJA}$
- (2) Free air, mounted or recommended copper pad area; thermal resistance RthJA junction to ambient
- (3) Mounted on infinite heatsink

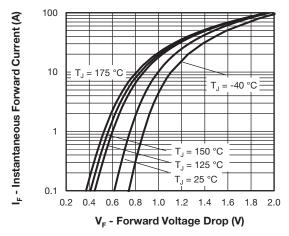


Fig. 1 - Typical Forward Voltage Drop Characteristics

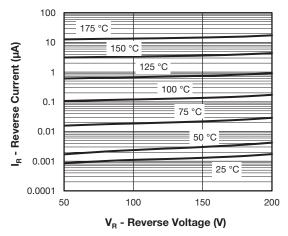


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



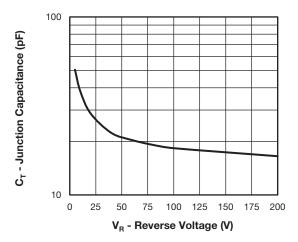


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

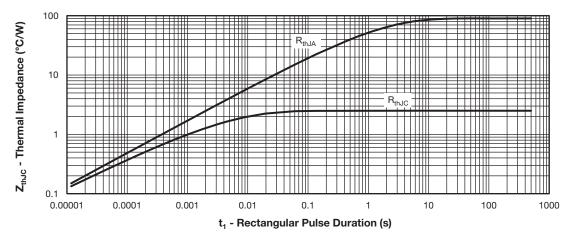


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

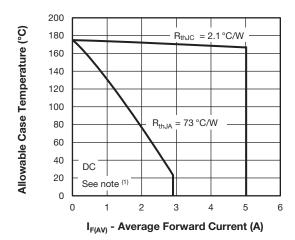


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

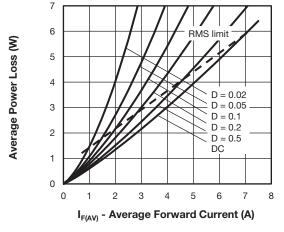


Fig. 6 - Forward Power Loss Characteristics

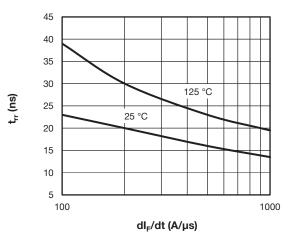
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_{R} (1 - D)$; I_{R} at V_{R1} = rated V_{R1}



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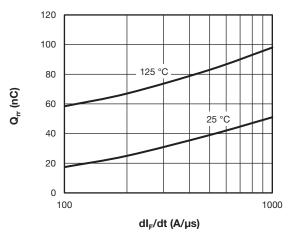
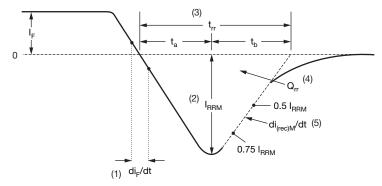


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_F$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

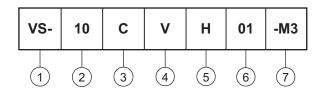
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (10 = 10 A)

Circuit configuration:

C = common cathode

4 - V = SlimDPAK

- Process type,

H = hyper fast recovery

6 - Voltage code (01 = 100 V)

7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

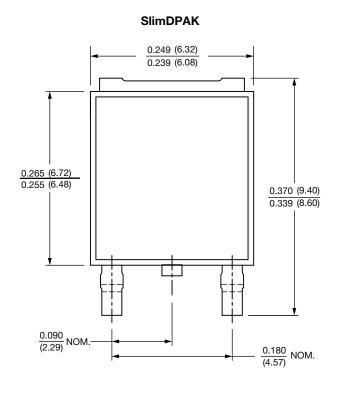
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-10CVH01-M3/I	4500	4500	13"diameter plastic tape and reel		

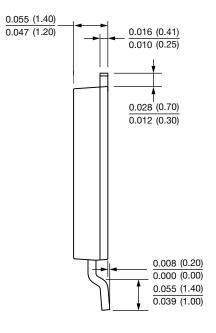
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96081</u>				
Part marking information	www.vishay.com/doc?96085			
Packaging information	www.vishay.com/doc?88869			



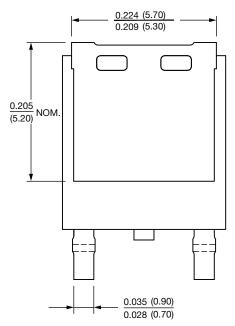
SlimDPAK

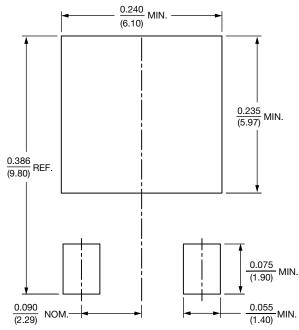
DIMENSIONS in inches (millimeters)





Mounting Pad Layout







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Vishay

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